16-channel High Voltage analog switch IC

ECN3298TF Product Specification   Rev.1

ECN3298 is 16-channel High Voltage analog switching IC with a bleed resistor on which latch-up free is realized by dielectric isolation technology.

High voltage and low ON-resistance MOS switches are used as output devices controlled by a 3.3V or 5V signal. The ECN3298 is most suited to Ultrasound Imaging applications.

Functions

* High voltage and low on-resistance MOS switches integrated.

* 16bit shift resister integrated.

* Integrated bleed resistors on one side of the outputs.

* Integrated clamping diodes for overvoltage protection positive overshoot.

Features

* Switch on-resistance: 19 Ω typ. (VPP=100V,VNN=-100V,ISIG=5mA, 25°C)

* Switch breakdown voltage: 220V

* Latch-up free CMOS and High-Voltage drive circuit.

* Power up/down sequence of power supply is free.
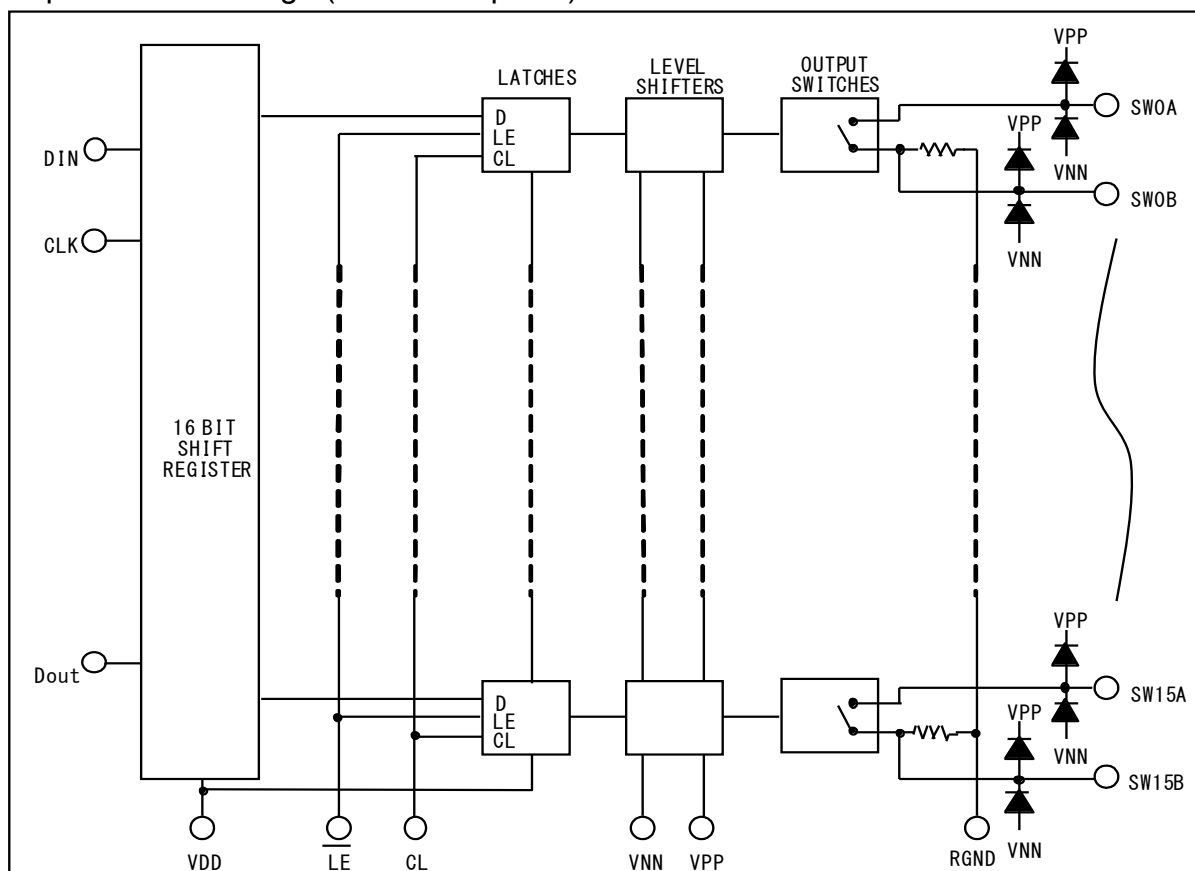
* 48-pin TQFP Package (RoHS compliant)

Fig.1 Block diagram

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1. General

This Specification shall be applied to the following semiconductor integrated circuit.

1) Parts name : ECN3298TF
2) Application : Ultrasound imaging scanner and others
3) Structure : Monolithic IC
4) Package : TQFP48

2. Absolute Maximum Ratings

Table 1　Absolute Maximum Ratings

No.	Items	Symbol	Terminal	Values	Unit	Note
1	Logic power supply voltage	VDD	VDD	-0.5 to +7.0	V	Ta＝25°C
2	VPP-VNN supply voltage	-	VPP, VNN	220	V	Ta＝25°C
3	VPP Positive high voltage supply	VPP	VPP	-0.5 to 200	V	Ta＝25°C
4	VNN negative high voltage supply	VNN	VNN	-200 to +0.5	V	Ta＝25°C
5	Logic input voltages	VDD	DIN, CLK, CL $\overline{LE}$	-0.5 to VDD+0.3	V	Ta＝25°C
6	Analog signal range	-	SW0 to SW15	VNN to VPP	V	Ta＝25°C
7	Operating junction temperature	Tjop	-	-20 to +125	^{o}C	
8	Storage temperature	Tstg	-	-55 to +150	^{o}C	
9	Power dissipation	Pw	-	1.0	W	TQFP48 Ta＝70°C

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3. Electrical Characteristics

3.1 DC Characteristics

Table 2   DC Characteristics   Ta=25°C   VDD=5V

No.	Items	Symbol	Spec			Unit	Test conditions	
			Min	Typ	Max			
1	Small signal switch on resistance	RONS	–	24	38	Ω	ISIG=5mA	VPP=40V, VNN=-160V
			–	17	27		ISIG=200mA	
			–	19	27		ISIG=5mA	VPP=100V, VNN=-100V
			–	15	24		ISIG=200mA	
			–	19	25		ISIG=5mA	VPP=160V, VNN=-40V
			–	15	25		ISIG=200mA	
2	Small signal switch on resistance matching	ΔRONS	–	5	20	%	VPP=100V, VNN=-100V ISW=5mA	
3	Large signal switch on resistance	RONL	–	16	—	Ω	VPP=100V VNN=-100V	ISIG=1A
4	Value of output bleed resistance	RINT	20	35	50	kΩ	Output switch to RGND IRINT=0.5mA	
5	Switch off leakage per switch	ISOL	–	1.0	10	μA	VSIG=VPP-10V, or VNN+10V	
6	DC offset switch (off)	DCOFF	–	10	100	mV	No load	
7	DC offset switch (on)	DCON	–	10	100	mV	No load	
8	Positive HV supply current	IPPQ1	–	10	50	μA	All SWs off	
9	Negative HV supply current	INNQ1	–	-10	-50	μA	All SWs off	
10	Positive HV supply current	IPPQ2	–	10	50	μA	All SWs on, ISW=5mA	
11	Negative HV supply current	INNQ2	–	-10	-50	μA	All SWs on, ISW=5mA	
12	IPP Supply current	IPP	–	–	7.0	mA	VPP=40V VNN=-160V	50kHz output switching frequency without load
			–	–	7.0		VPP=100V VNN=-100V	
			–	–	8.0		VPP=160V VNN=-40V	
13	INN Supply current	INN	–	–	7.0	mA	VPP=40V VNN=-160V	50kHz output switching frequency without load
			–	–	7.0		VPP=100V VNN=-100V	
			–	–	8.0		VPP=160V VNN=-40V	
14	Logic supply average current	IDD	–	–	4.0	mA	fCLK=5MHz,VDD=5.0V	
15	Logic supply quiescent current	IDDQ	–	–	10	μA		
16	Data out source current	ISOR	0.45	0.70	–	mA	VOUT=VDD-0.7V	
17	Data out sink current	ISINK	0.45	0.70	–	mA	VOUT=0.7V	

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3.2 AC Characteristics

Table 3 AC Characteristics   Ta=25°C   VDD=5V

No.	Items	Symbol	Spec			Unit	Test conditions
			Min	Typ	Max		
1	SW Turn on time	tON	–	–	5.0	μs	VSIG=VPP-10V, RL=10kΩ
2	SW Turn off time	tOFF	–	–	5.0	μs	VSIG=VPP-10V, RL=10kΩ
3	Clock frequency	fCLK	–	–	30	MHz	50% duty cycle, fData=fCLK/2 VDD= 5.0V
			–	–	20	MHz	50% duty cycle, fData=fCLK/2 VDD=3.3V
4	Clock delay time to data out	tDO	16	–	55	ns	DOUT terminal,VDD=3.3V
			12	–	42	ns	DOUT terminal,VDD=5.0V
5	Output voltage spike	+VSPK	–	–	150	mV	VPP=40V, VNN=-160V, RL=50Ω
		-VSPK	–	–	-150		
		+VSPK	–	–	150		VPP=100V, VNN=-100V, RL=50Ω
		-VSPK	–	–	-150		
		+VSPK	–	–	150		VPP=160V, VNN=-40V, RL=50Ω
		-VSPK	–	–	-150		

Table 4   AC Characteristics (for reference purpose only)   Ta=25°C   VDD=5V

No.	Items	Symbol	Spec			Unit	Condition
			Min	Typ	Max		
1	Off capacitance SW to GND	CSG (off)	–	6	–	pF	0V, 1MHz
2	On Capacitance SW to GND	CSG (on)	–	15	–	pF	0V, 1MHz
3	SW off isolation	KO	-30	-33	–	dB	fsw=5MHz, 1kΩ//15pF load
			-54	-60	–	dB	fsw=5MHz, 50Ω load
4	SW Crosstalk	KCR	-54	-60	–	dB	fsw=5MHz, 50Ω load

Note: These items are not tested when shipped.

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4. Recommended Operating Conditions

Please operate in use within the limit of recommended operating conditions detailed in Table 5.

Table 5 Recommended Operating Conditions

No	Items	Symbol	Recommended Value
1	Logic power supply voltage	VDD	3.0V to 5.5V
2	Positive high voltage supply	VPP	40V to 160V
3	Negative high voltage supply	VNN	-160V to 0V
4	VPP-VNN supply voltage	-	40V to 200V
5	High-level input voltage	VIH	0.9VDD to VDD
6	Low-level input voltage	VIL	0V to 0.1VDD
7	Analog signal voltage peak to peak	VSIG	VNN to VPP
8	Operating free air-temperature	Ta	0°C to 70°C
9	Switching frequency	Fsw	50kHz max, Duty Cycle=50%
10	Set up time for $\overline{LE}$	TSD	Min.60ns
11	Pulse width of $\overline{LE}$	TWLE	Min.40ns
12	Time width of CL	TWCL	Min.40ns
13	Set up time DATA to Clock	TSU	Min.10ns
14	Hold time DATA from Clock	Th	Min.10ns
15	Maximum VSIG Slew Rate	dV/dt	Max.30V/ns

Attention ;
1) Power up/down sequence of power supply is arbitrary except GND terminal of IC must be powered-up first and powered-down last.
2) It is indispensable to make there are not to exceed a maximum rated voltage by the occurrence of the excessive voltage in case of investing and cutting of the power supply.

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5. Test Circuit

a) Switch OFF Leakage

b) DC Offset ON/OFF

c) TON/TOFF

$$K_o = 20\log(V_{OUT}/V_{IN})$$

d) Off Isolation

$$K_{cr} = 20\log(V_{OUT}/V_{IN})$$

e) Crosstalk

f) Output Voltage Spike

Fig. 2 Test Circuit

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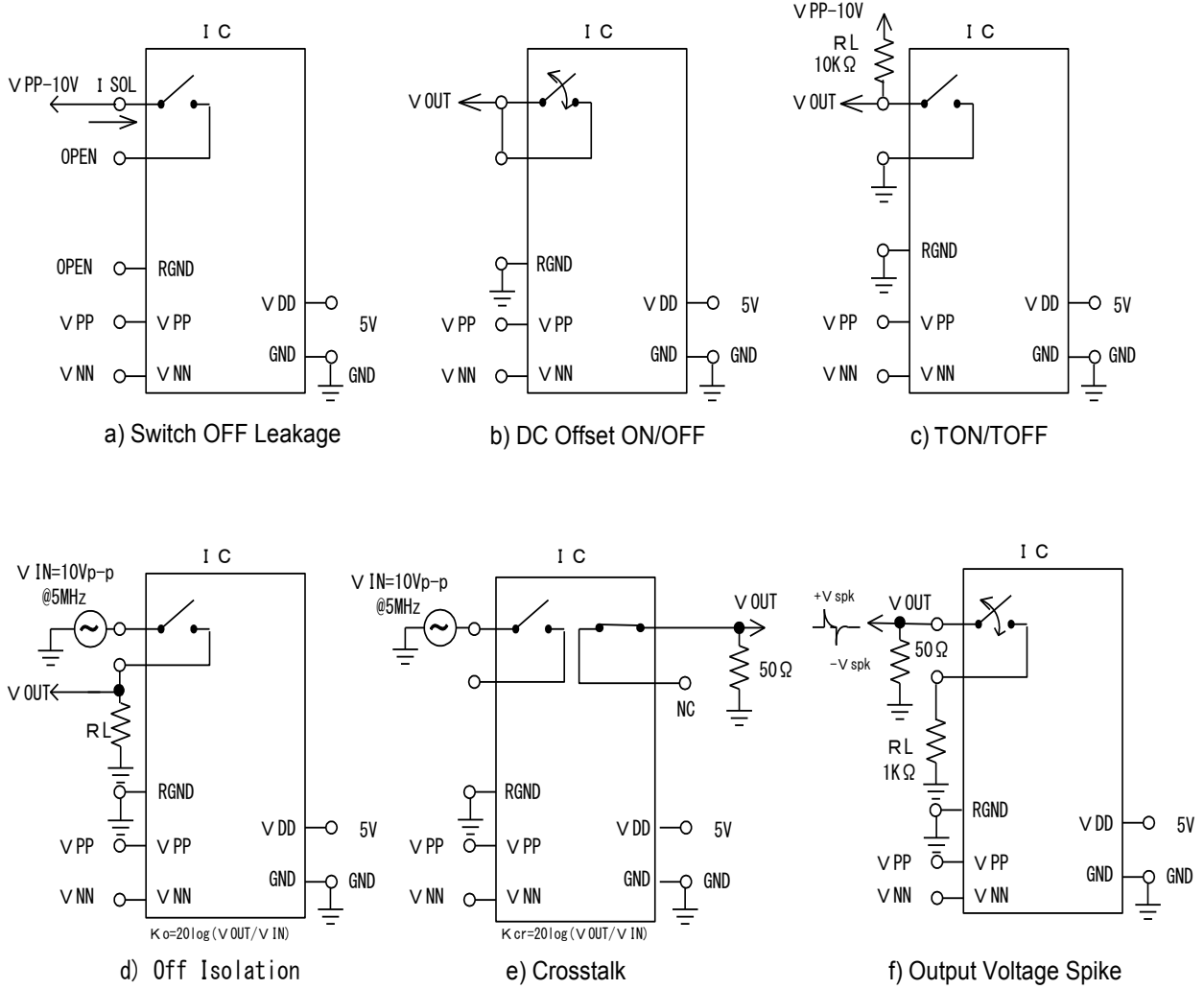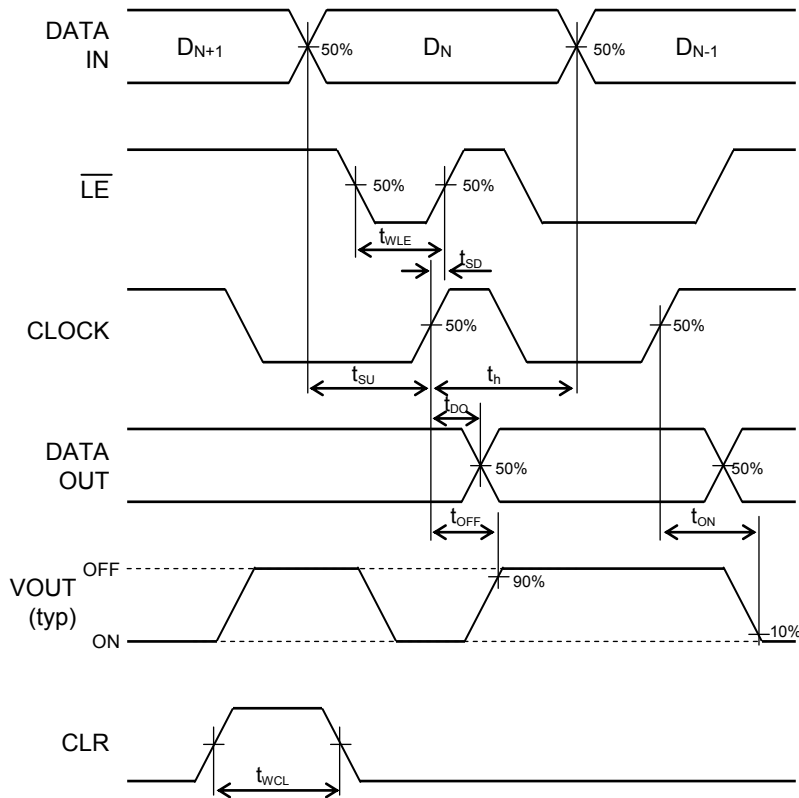## 6. Timing Waveforms

Fig. 3   Timing Waveforms

<u>Note</u>
1. Serial data is clocked in on the rising edge of CLK.
2. The switches go to a state retaining their present condition on the rising edge of LE.
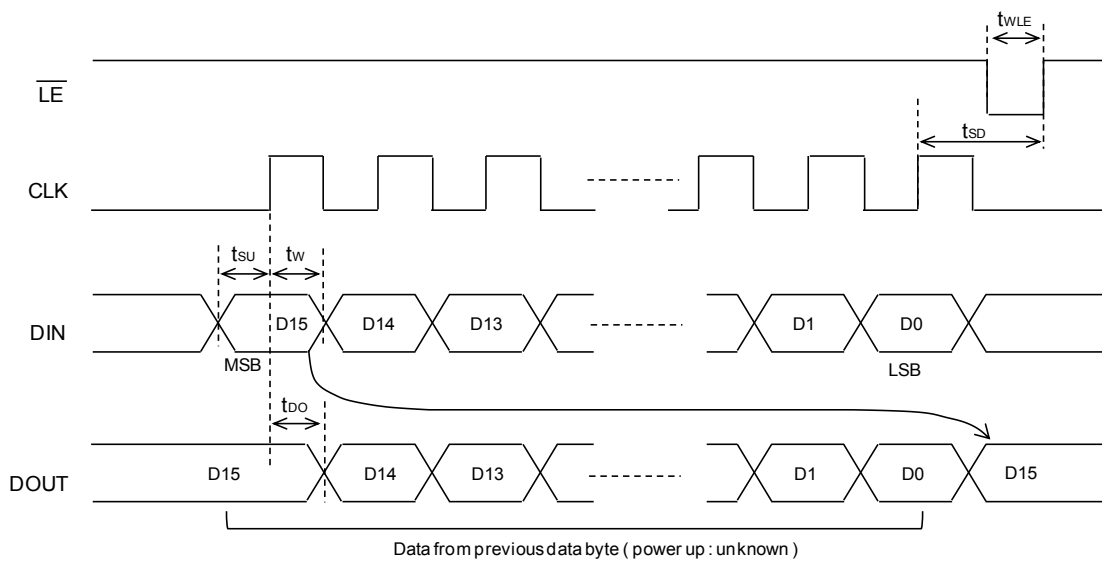

Fig. 4 LATCH ENABLE Timing waveform

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7. Truth Table

Table 6 Truth table

D0	D1	D2	D3	D4	D5	D6	D7	$\overline{LE}$	CL	SW0	SW1	SW2	SW3	SW4	SW5	SW6	SW7
L								L	L	OFF							
H								L	L	ON							
	L							L	L		OFF						
	H							L	L		ON						
		L						L	L			OFF					
		H						L	L			ON					
			L					L	L				OFF				
			H					L	L				ON				
				L				L	L					OFF			
				H				L	L					ON			
					L			L	L						OFF		
					H			L	L						ON		
						L		L	L							OFF	
						H		L	L							ON	
							L	L	L								OFF
							H	L	L								ON
X	X	X	X	X	X	X	X	H	L	HOLD PREVIOUS STATE							
X	X	X	X	X	X	X	X	X	H	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF

D8	D9	D10	D11	D12	D13	D14	D15	$\overline{LE}$	CL	SW8	SW9	SW10	SW11	SW12	SW13	SW14	SW15
L								L	L	OFF							
H								L	L	ON							
	L							L	L		OFF						
	H							L	L		ON						
		L						L	L			OFF					
		H						L	L			ON					
			L					L	L				OFF				
			H					L	L				ON				
				L				L	L					OFF			
				H				L	L					ON			
					L			L	L						OFF		
					H			L	L						ON		
						L		L	L							OFF	
						H		L	L							ON	
							L	L	L								OFF
							H	L	L								ON
X	X	X	X	X	X	X	X	H	L	HOLD PREVIOUS STATE							
X	X	X	X	X	X	X	X	X	H	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF

X = Don't care

Note
1. *The 16 Switches operate independently.*
2. *When $\overline{LE}$ is low, the shift register data flows through the latch.*
3. *Shift register clocking has no effect on the switch states if $\overline{LE}$ is high.*
4. *When switch 15 is ON, DOUT is high.*
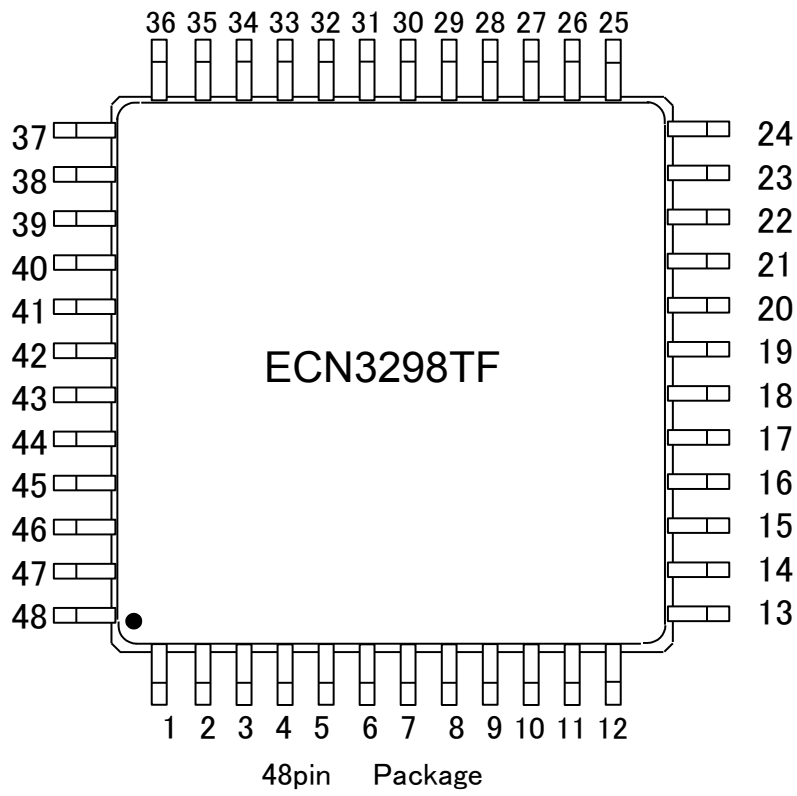5. *The clear input overrides all other inputs.*

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8. Pin Configuration
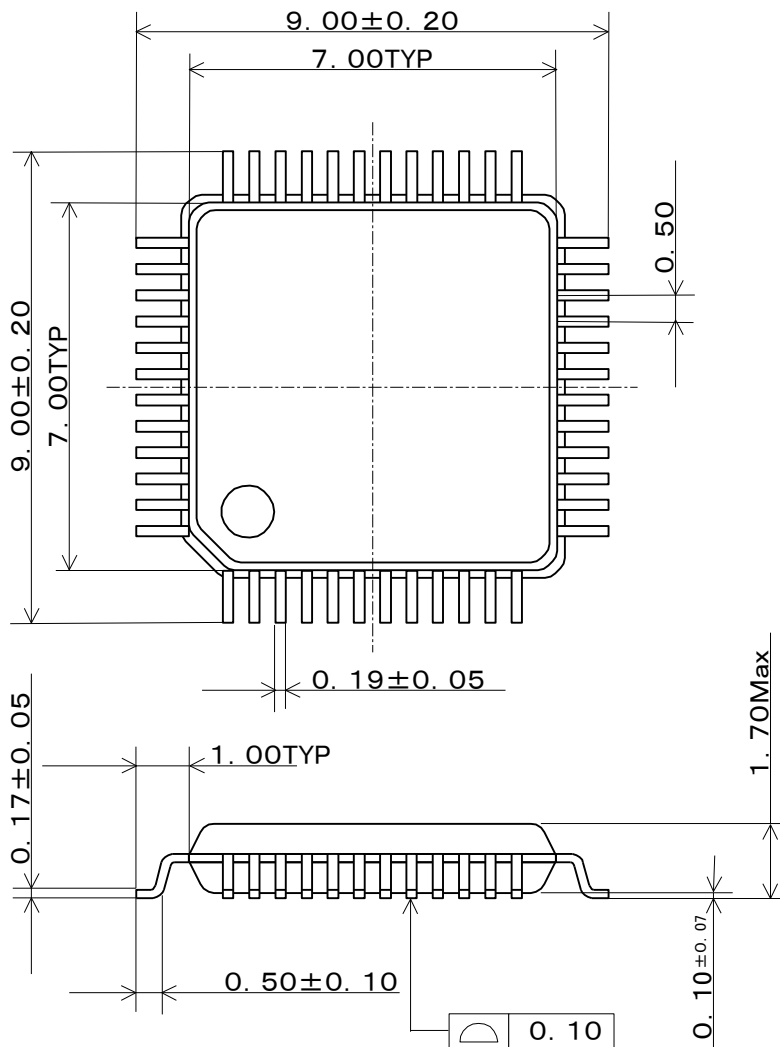
ECN3298TF TQFP48 (48Pin TQFP)

Table7. Pin Configuration

Pin	Name	Functions	Note
1	N/C	No connection.	*1
2	N/C	No connection.	*1
3	SW4B	Analog Switch 4 (Integrated output bleed resistor)	
4	SW4A	Analog Switch 4	
5	SW3B	Analog Switch 3 (Integrated output bleed resistor)	
6	SW3A	Analog Switch 3	
7	SW2B	Analog Switch 2 (Integrated output bleed resistor)	
8	SW2A	Analog Switch 2	
9	SW1B	Analog Switch 1 (Integrated output bleed resistor)	
10	SW1A	Analog Switch 1	
11	SW0B	Analog Switch 0 (Integrated output bleed resistor)	
12	SW0A	Analog Switch 0	
13	VNN	Negative High Voltage Supply.	*2
14	N/C	No connection.	*1
15	VPP	Positive High Voltage Supply.	*2
16	N/C	No connection.	*1
17	GND	Ground	
18	VDD	Logic Supply Voltage	
19	DIN	Serial Data Input	
20	CLK	Serial Clock Input	
21	$\overline{\text{LE}}$	Latch-Enable Input	
22	CLR	Latch-Clear Input	
23	DOUT	Serial Data Output	
24	RGND	Ground. Connect to Bleed Resister.	*3
25	SW15B	Analog Switch 15 (Integrated output bleed resistor)	
26	SW15A	Analog Switch 15	
27	SW14B	Analog Switch 14 (Integrated output bleed resistor)	
28	SW14A	Analog Switch 14	
29	SW13B	Analog Switch 13 (Integrated output bleed resistor)	
30	SW13A	Analog Switch 13	
31	SW12B	Analog Switch 12 (Integrated output bleed resistor)	
32	SW12A	Analog Switch 12	
33	SW11B	Analog Switch 11 (Integrated output bleed resistor)	
34	SW11A	Analog Switch 11	
35	N/C	No connection.	*1
36	N/C	No connection.	*1
37	SW10B	Analog Switch 10 (Integrated output bleed resistor)	
38	SW10A	Analog Switch 10	
39	SW9B	Analog Switch 9 (Integrated output bleed resistor)	
40	SW9A	Analog Switch 9	
41	SW8B	Analog Switch 8 (Integrated output bleed resistor)	
42	SW8A	Analog Switch 8	
43	SW7B	Analog Switch 7 (Integrated output bleed resistor)	
44	SW7A	Analog Switch 7	
45	SW6B	Analog Switch 6 (Integrated output bleed resistor)	
46	SW6A	Analog Switch 6	
47	SW5B	Analog Switch 5 (Integrated output bleed resistor)	
48	SW5A	Analog Switch 5	

Note 1. NOT connected on chip internal.
  2. High voltage supply.
  3. Connected all SW_B terminals with a bleed resistor on chip internal.

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48pin   Package

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9. Package Outline

Units : mm

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10. Marking spec

```
          (a)  (b)  (c)  (d)  (e)

          E    C    N    3    2

          9    8    T    F

  Blank

     ○  ←  INDEX pin
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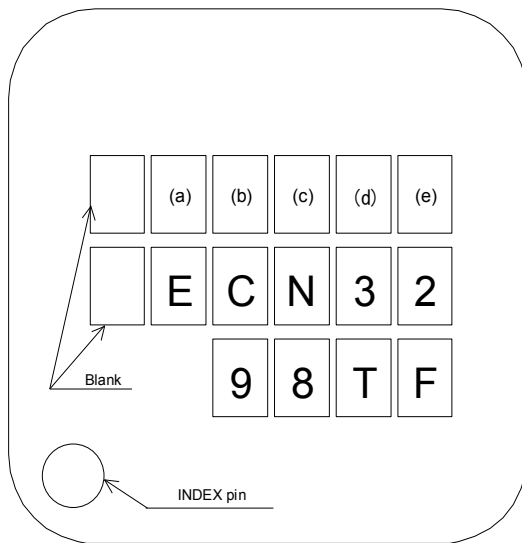
Lot numbering rule

(a) :Year code (Least significant digit of Assembled year (A.D.))
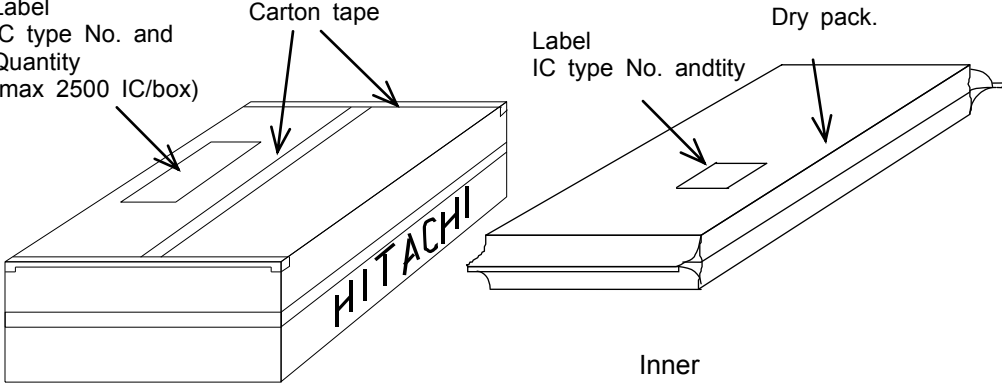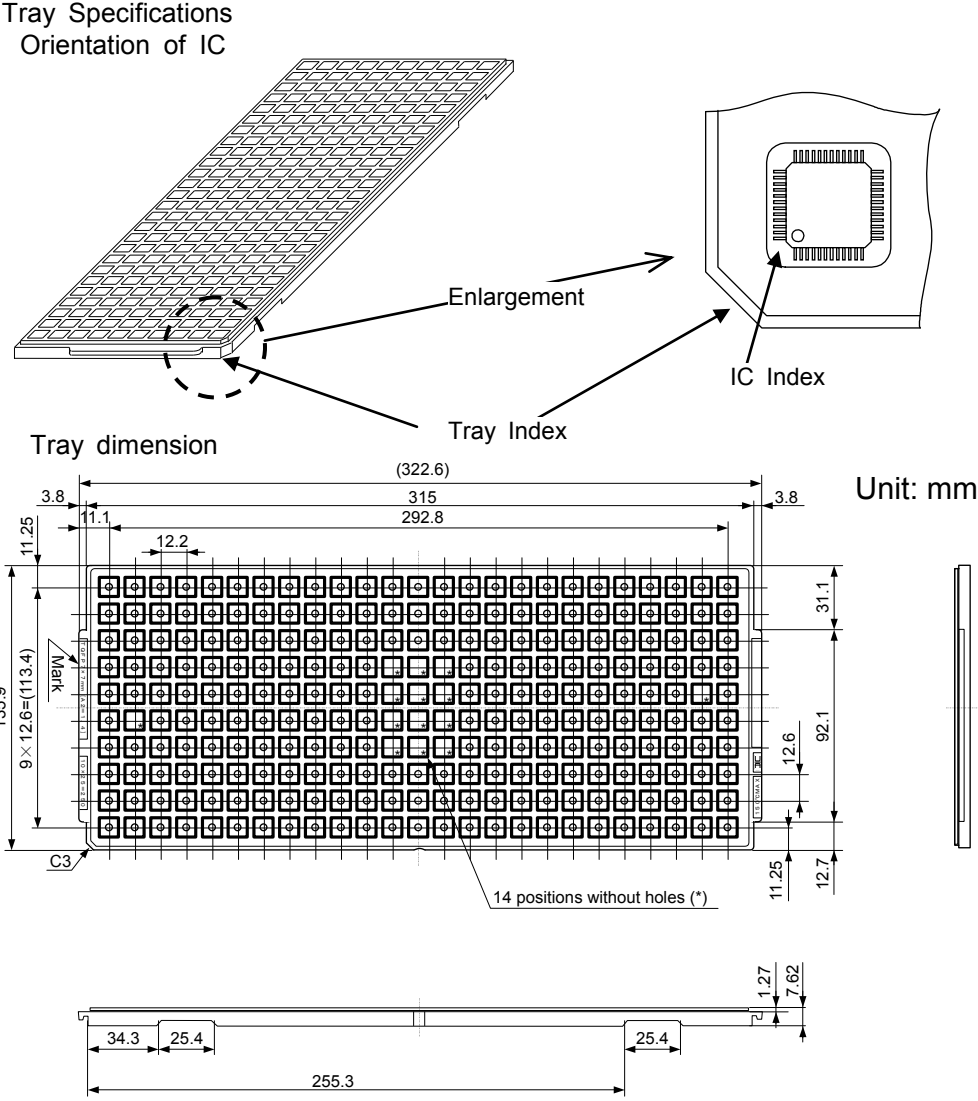
(b) :Month code (Refer to following table.)

Month	1	2	3	4	5	6	7	8	9	10	11	12
Month code	A	B	C	D	E	K	L	M	N	X	Y	Z

(c),(d),(e) :Serial number within year/month code

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11 Packing Form

Packaging details are as shown below.

1.Outer and inner packing	Label IC type No. and Quantity (max 2500 IC/box) Carton tape Label IC type No. andtity Dry pack. HITACHI Inner Outer box (cardboard box)
2.Tray	Tray Specifications Orientation of IC Enlargement IC Index Tray Index Tray dimension Unit: mm (322.6) 3.8 315 3.8 11.1 292.8 11.25 12.2 31.1 135.9 9×12.6=(113.4) Mark 92.1 12.6 11.25 12.7 C3 14 positions without holes (*) 1.27 7.62 34.3 25.4 25.4 255.3 (1) Material of tray is PPE containing carbon and static proof. (2) Packing quantity is max 250 IC/Tray. (3) Maximum heat resistant temperature is 150deg.

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12 Inspection
Hundred percent inspections shall be conducted on electric characteristics.

13. Precautions for use

13.1 Countermeasures against Electrostatic Discharge (ESD)

(a) Customers need to take precautions to protect ICs from electrostatic discharge (ESD). The material of the container or any other device used to carry ICs should be free from ESD, which can be caused by vibration during transportation. Use of electrically conductive containers is recommended as an effective countermeasure.

(b) Everything that touches ICs, such as the work platform, machine, measuring equipment, and test equipment, should be grounded.

(c) Workers should be high-impedance grounded (100kΩ to 1MΩ) while working with ICs, to avoid damaging the ICs by ESD.

(d) Friction with other materials, such as high polymers, should be avoided.

(e) When carrying a PCB with a mounted IC, ensure that the electric potential is maintained at a constant level using the short-circuit terminals and that there is no vibration or friction.

(f) The humidity at an assembly line where ICs are mounted on circuit boards should be kept around 45 to 75 percent using humidifiers or such. If the humidity cannot be controlled effectively, using ionized air blowers (ionizers) is effective.

13.2 Output Short-Circuit Protection

A short circuit (ex. load short) could damage this IC (the product of Hitachi Power Semiconductor Device, hereinafter called "HPSD's IC"). External protection is needed to prevent HPSD's IC breakdown.

13.3 Maximum ratings

Regardless of changes in external conditions during use HPSD's IC, the "maximum ratings" described in this document should never be exceeded when designing electronic circuits that employ HPSD's IC. If maximum ratings are exceeded, HPSD's IC may be damaged or destroyed. In no event shall Hitachi Power Semiconductor Device (hereinafter called "HPSD") be liable for any failure in HPSD's IC or any secondary damage resulting from use at a value exceeding the maximum ratings.

13.4 Derating Design

Continuous high-load operation (high temperatures, high voltages, large currents) should be avoided and derating design should be applied, even within the ranges of the maximum ratings, to ensure reliability.

13.5 Safe Design

The HPSD's IC may fail due to accidents or unexpected surge voltages. Accordingly, adopt safe design features, such as redundancy and measures to prevent misuse, in order to avoid extensive damage in the event of a failure.

13.6 Application

If HPSD's IC is applied to the following uses where high reliability is required, obtain the document of permission from HPSD in advance.
・Automobile, Train, Vessel, etc.
Do not apply HPSD's IC to the following uses where extremely high reliability is required.
・Nuclear power control system, Aerospace instrument, Life-support-related medical equipment, etc.

13.7 Soldering

Lead-free solder is used for coating pins and the tab of this IC. Refer to"Instructions for Use of Hitachi High-Voltage Monolithic ICs" for soldering conditions.

13.8 Others

See "Instructions for Use of Hitachi High-Voltage Monolithic ICs" for other precautions and instructions on how to deal with these kinds of products.

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14. Usage

(1) HPSD warrants that the HPSD products have the specified performance according to the respective specifications at the time of its sale. Testing and other quality control techniques of the HPSD products by HPSD are utilized to the extent HPSD needs to meet the specifications described in this document. Not every device of the HPSD products is specifically tested on all parameters, except those mandated by relevant laws and/or regulations.

(2) Following any claim regarding the failure of a product to meet the performance described in this document made within one month of product delivery, all the products in relevant lot(s) shall be re-tested and re-delivered. The HPSD products delivered more than one month before such a claim shall not be counted for such response.

(3) HPSD assumes no obligation nor makes any promise of compensation for any fault which should be found in a customer's goods incorporating the products in the market. If a product failure occurs for reasons obviously attributable to HPSD and a claim is made within six months of product delivery, HPSD shall offer free replacement or payment of compensation. The maximum compensation shall be the amount paid for the products, and HPSD shall not assume responsibility for any other compensation.

(4) HPSD reserves the right to make changes in this document and to discontinue mass production of the relevant products without notice. Customers are advised to confirm specification of the product of inquiry before purchasing of the products that the customer desired. Customers are further advised to confirm before purchasing of such above products that the product of inquiry is the latest version and that the relevant product is in mass production status if the purchasing of the products by the customer is suspended for one year or more.

(5) When you dispose of HPSD products and/or packing materials, comply with the laws and regulations of each country and/or local government. Conduct careful preliminary studies about environmental laws applying to your products such as RoHS, REACH. HPSD shall not assume responsibility for compensation due to contravention of laws and/or regulations.

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◆Appendix-Supplementary Data

Please read below contents before using this product.

Function Discription

1. Bleed resistor
   ECN3298TF feature integrated 35kΩ bleed resistor to discharge capacitive Loads such as piezoelectric transducers. One side of analog switch terminal(SW_B) is coneccted RGND with ableed resistor.

2. Overvoltage Protection
   ECN3298TF feature clamping diodes to protect circuit against the overvoltage exceed VPP or VNN. ALL analog switches connect VPP and VNN terminals with clamping diode. Normaly, switch input voltage must not exceed VNN and VPP, and maximum current flows through the clamping diode should be less than 1A.

3. Power supply seaquence
   ECN3298TF doesn't require special sequencing of the VPP, VNN, and VDD supply voltages. However, logic state is unsettled when power-up. After power-up, please refer to the truth table(Page.7 Table.7) and set the data of shift register.

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Precautions for Safe Use and Notices

If semiconductor devices are handled inappropriate manner, failures may result. For this reason, be sure to read "Precaution for Use" before use.

⚠		This mark indicates an item about which caution is required.
⚠	**CAUTION**	This mark indicates a potentially hazardous situation which, if not avoided, may result in minor or moderate injury and damage to property.

⚠ CAUTION

(1) Regardless of changes in external conditions during use "absolute maximum ratings" should never be exceed in designing electronic circuits that employ semiconductors.
In the case of pulse use, furthermore,"safe operating area (SOA)"precautions should be observed.

(2) Semiconductor devices may experience failures due to accident or unexpected surge voltages. Accordingly, adopt safe design features, such as redundancy or prevention of erroneous action, to avoid extensive damage in the event of a failure.

(3) In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, life-support-related medical equipment, fuel control equipment and various kinds of safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of user's fail-safe precautions or other arrangement. Or consult Hitachi's sales department staff.

(If a semiconductor devices fails, there may be cases in which the semiconductor device, wiring or wiring pattern will emit smoke or cause a fire or in which the semiconductor device will burst)

NOTICES

1. This Data sheet contains the specifications, characteristics (in figures and tables), dimensions and handling notes concerning power semiconductor products (hereinafter called "products") to aid in the selection of suitable products.

2. The specifications and dimensions, etc. stated in this Data sheet are subject to change without prior notice to improve products characteristics. Before ordering, purchasers are advised to contact Hitachi's sales department for the latest version of this Data sheet and specifications.

3. In no event shall Hitachi be liable for any damage that may result from an accident or any other cause during operation of the user's units according to this Data sheet. Hitachi assumes to responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in this Data sheet.

4. In no event shall Hitachi be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5. No license is granted by this Data sheet under any patents or other rights of any third party or Hitachi, Ltd.

6. This Data sheet may not be reproduced or duplicated, in any form, in whole or in part, without the expressed written permission of Hitachi, Ltd.

7. The products (technologies) described in this Data sheet are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations.